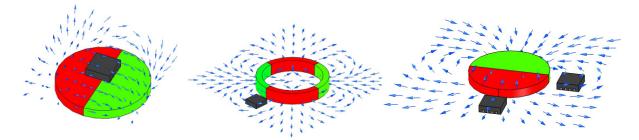




- AMR Sensor with 180° period
- for the use at moderate field strengths
- high accuracy
- tiny TDFN package
- various packages available

#### DESCRIPTION

The KMT32B is a magnetic field sensor based on the anisotropic magneto resistance effect, i.e. it is sensing the **magnetic field direction** independently on the magnetic field strength for applied field strengths H>25 kA/m. The sensor contains two parallel supplied Wheatstone bridges, which enclose a sensitive angle of 45 degrees.



A rotating magnetic field in the surface parallel to the chip (x-y plane) will deliver two independent sinusoidal output signals, one following a  $cos(2\alpha)$  and the second following a  $sin(2\alpha)$  function,  $\alpha$  being the angle between sensor and field direction (see Figure 2).

#### **FEATURES**

- Contactless angular position
- Design optimized linearity
- High accuracy
- Low cost, low power
- Self diagnosis feature
- User has complete control over signal evaluation
- Attractive SMD packages
- High rotational speed up to 30,000 rpm
- Extended operating temperature range (-40 °C to +150 °C, +160 °C on request)
- Ideal for harsh environments due to magnetic sensing principle
- RoHS compliant (lead free)

## **APPLICATIONS**

- Absolute and incremental angle measurement
- Motor motion control
- Robotics
- Camera positioning
- Potentiometer replacement
- · Position measurement in medical applications
- Automotive (steering angle, torque)



## CHARACTERISTIC VALUES

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
A. Operating Limits		1		1		1
Max. supply voltage	Vcc <sub>,max</sub>				10	V
Max. current (single bridge)	Icc,max				4	mA
Operating temperature	T <sub>op</sub>		-40		+150	°C
Storage temperature	T <sub>st</sub>		-40		+150	°C
B. Sensor Specifications (T	=25 ℃)	·	·			
Supply voltage	Vcc			5		V
Resistance (single bridge)	R₀		2400	3000	3600	Ω
Output signal range	ΔV <sub>n</sub> /Vcc	Condition A, B	16	20		mV/V
Offset voltage	Voff/Vcc	Condition A, B	-1	0	+1	mV/V
Angular inaccuracy	Δα	Condition A, B		0.05	0.2	deg
Angular hysteresis	ΔαΗ	Condition A, B			0.1	deg
C. Sensor Specifications		·	·			
TC of amplitude	TCSV	Condition A, C	-0.36	-0.32	-0.28	%/K
TC of resistance	TCBR	Condition A, C	+0.27	+0.32	+0.37	%/K
TC of offset	TCVoff	Condition A, C	-4	0	+4	μV/V/K

Stress above one or more of the limiting values may cause permanent damage to the device. Exposure to limiting values for extended periods may affect device reliability.

#### **MEASUREMENT CONDITIONS**

Parameter	Symbol	Unit	Condition
Condition A: Set Up Condi	tions	•	
Ambient temperature	Т	°C	T = 23±5 °C (unless otherwise noted)
Supply voltage	Vcc	V	Vcc = 5 V
Applied magnetic field	Н	kA/m	H = 25 kA/m
Condition B: Sensor Speci	fications (T=2	5 ℃, 360°	turn,H=25 kA/m,Vo <sub>max</sub> >0,Vo <sub>min</sub> <0)
Output signal range	$\Delta V_n/Vcc$	mV/V	$\Delta V_n / Vcc = (Vo_{max} - Vo_{min}) / Vcc$
Offset voltage	Voff/Vcc	mV/V	Voff = (Vo <sub>max</sub> + Vo <sub>min</sub> )/Vcc
Angular inaccuracy	Δα	deg	$\Delta \alpha = MAX  \alpha_0 - \alpha $ max. angular difference between actual value $\alpha_0$ and measured angle; offset voltage error contributions not included
Angular hysteresis	ΔαΗ	deg	$\Delta \alpha H = MAX   \alpha_{left turn} - \alpha_{right turn}  $ max. angular difference between left and right turn



### **MEASUREMENT CONDITIONS**

Parameter	Symbol	Unit	Condition		
Condition C: Sensor Specifications (T=-25 ℃, +125 ℃)					
Ambient temperatures	Т	°C	$T_1 = -25 \ ^{\circ}C,  T_0 = +25 \ ^{\circ}C,  T_2 = +125 \ ^{\circ}C$		
TC of amplitude	TCSV	%/K	$TCV = \frac{1}{(T_2 - T_1)} \cdot \frac{\frac{\Delta Vn}{Vcc}(T_2) - \frac{\Delta Vn}{Vcc}(T_1)}{\frac{\Delta Vn}{Vcc}(T_1)} \cdot 100\%$		
TC of resistance	TCBR	%/K	$TCR = \frac{1}{(T_2 - T_1)} \cdot \frac{R(T_2) - R(T_1)}{R(T_1)} \cdot 100\%$		
TC of offset	TCVoff	(μV/V)/ Κ	$TCVoff = \frac{Voff(T_2) - Voff(T_1)}{(T_2 - T_1)}$		

#### **BLOCK DIAGRAM**

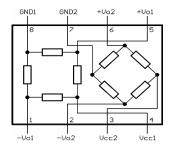
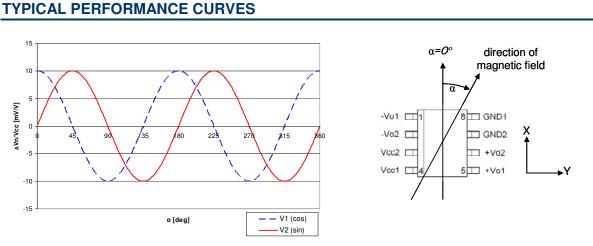


Figure 1: Circuit Diagram

The KMT32B magnetic field sensor is suited for high precision angle measurement applications under low field conditions (regularly  $H_0 = 25$  kA/m, for example generated with reference magnet 67.044 Magnetfabrik Bonn @ 5,2 mm distance. With reduced accuracy the applicable down to  $H_0 = 8$  kA/m; beware of earth's magnetic field!).

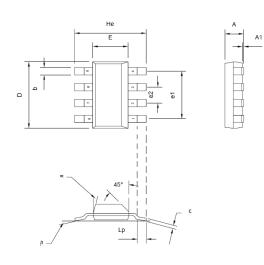


#### Figure 2: Characteristic curves for KMT32B



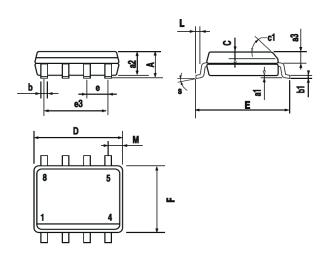
# PACKAGES

SM-8



Dim	Millimetres			Inches		
	Min	Тур	Max	Min	Тур	Max
А	-	-	1.7	-	-	0.067
A1	0.02	-	0.1	0.0008	-	0.004
b	-	0.7	-	-	0.028	-
с	0.24	-	0.32	0.009	-	0.013
D	6.3	-	6.7	0.248	I	0.264
Е	3.3	-	3.7	0.130	-	0.145
e1	-	4.59	-	-	0.180	-
e2	-	1.53	-	-	0.060	-
He	6.7	-	7.3	0.264	-	0.287
Lp	0.9	-	-	0.035	-	-
α	-	-	15°	-	-	15°
β	-	10°	-	-	10°	-

SO-8



DIM.	mm				inch		
DIWI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			1.75			0.069	
a1	0.1		0.25	0.004		0.010	
a2			1.65			0.065	
a3	0.65		0.85	0.026		0.033	
b	0.35		0.48	0.014		0.019	
b1	0.19		0.25	0.007		0.010	
С	0.25		0.5	0.010		0.020	
c1		45° (typ.)					
D (1)	4.8		5.0	0.189		0.197	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		3.81			0.150		
F (1)	3.8		4.0	0.15		0.157	
L	0.4		1.27	0.016		0.050	
М			0.6			0.024	
S	8° (max.)						



2

0,30

0,375

8

 $\mathbf{P} \mathbf{P} \mathbf{Q}$ 

1.80

פפרס

99

80

5

# PACKAGES

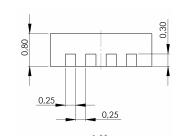
#### TDFN

unit: mm

2,50

The bottom plate is designated to be a heat sink. It has no electrical connection to any pin.

*The sensitive area is positioned in the center of the housing.* 

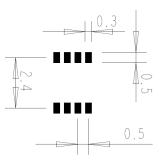


RECOMMENDED SOLDER PAD LAYOUT FOR TDFN

2,50

**КМТ** 32В

Ο



## PIN ASSIGNMENT (DIE, SO8, SM8, TDFN)

Pin	Symbol	Function	
1	-V <sub>o1</sub>	negative output bridge 1	
2	-V <sub>o2</sub>	negative output bridge 2	
3	V <sub>cc2</sub>	positive supply voltage bridge 2	
4	V <sub>cc1</sub>	positive supply voltage bridge 1	
5	+V <sub>o1</sub>	positive output bridge 1	
6	+V <sub>o2</sub>	positive output bridge 2	
7	GND <sub>2</sub>	negative supply voltage bridge 2	
8	GND <sub>1</sub>	negative supply voltage bridge 1	

#### SOLDER PROFILE

Recommended solder reflow process according to IPC/JEDEC J-STD-020D (Pb-Free Process)



## TAPE AND REEL PACKAGING INFORMATION

Description	Reel size	Units/reel	Pin 1 orientation	Note
KMT32B/TD	7"	3,000	Top-right of sprocket hole side	
KMT32B/SO	13"	2,500	Top-left of sprocket hole side	
KMT 32B/SM	7"	1,000	Top-right of sprocket hole side	

#### **ORDERING CODE**

Device	Package	MOQ	Part Number
KMT 32B	die	1 wafer	on request
KMT 32B/SM	SM-8	1 reel	on request
KMT 32B/SO	SO-8	1 reel	G-MRCO-015
KMT 32B/TD	TDFN 2.5 x 2.5	1 reel	G-MRCO-016

## **ORDERING INFORMATION**

Measurement Specialties, Inc. 1000 Lucas Way Hampton, VA 23666 Tel: 1-800-555-1551 Fax: 1-757-766-4297 Email: sales@meas-spec.com Web: www.meas-spec.com	Europe MEAS Deutschland GmbH Hauert 13, D-44227 Dortmund, Germany. Phone: +49-(0)231-9740-0 Fax: +49-(0)231-9740-20 Email: info.de@meas- spec.com Web: www.meas-spec.com	Measurement Specialties China Ltd. No. 26, Langshan Road, Shenzhen High-tech Park (North) Nanshan District, Shenzhen, China 518107 Phone: +86-755-33305088 Fax: +86-755-33305099 Email: info.cn@meas-spec.com Web: www.meas-spec.com
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